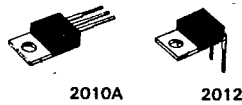


**2SD330,
331**



NPN/PNP Triple Diffused Planar Silicon Transistors

T-33-09

**2SB514,
515**

Low Frequency Power Amp Applications

©397D

Especially suited for use in output stage of 10W AF Power amp. The only difference between B514 and D515 lies in package design; and the same is true of D330 and D331. The B514 and D330 can be connected to form a complementary pair; and the same is true of B515 and D331.

() : 2SB514, 514.

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

			unit
Collector to Base Voltage	V_{CB0}	(-)50	V
Collector to Emitter Voltage	V_{CE0}	(-)50	V
Emitter to Base Voltage	V_{EB0}	(-)5	V
Collector Current	I_C	(-)2	A
Peak Collector Current	i_{cp}	(-)5	A
Collector Dissipation	P_C	1.75	W
	$T_C=25^\circ\text{C}$	20	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

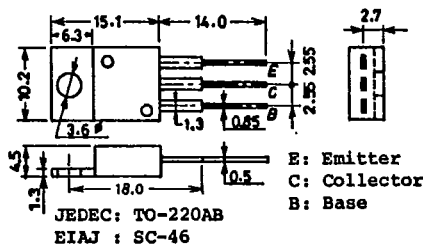
Electrical Characteristics at $T_a=25^\circ\text{C}$

			min	typ	max	unit
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)20\text{V}, I_E=0$		(-)0.1		mA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$		(-)1.0		mA
DC Current Gain	$h_{FE}(1)$	$V_{CE}=(-)2\text{V}, I_C=(-)1\text{A}$	40*		320*	
	$h_{FE}(2)$	$V_{CE}=(-)2\text{V}, I_C=(-)0.1\text{A}$	35			
Gain Bandwidth Product	f_T	$V_{CE}=(-)5\text{V}, I_C=(-)0.5\text{A}$		8		MHz
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2\text{A}, I_B=(-)0.2\text{A}$		(-)1.0		V
Base to Emitter Voltage	V_{BE}	$I_C=(-)1\text{A}, V_{CE}=(-)5\text{V}$		(-)1.5		V

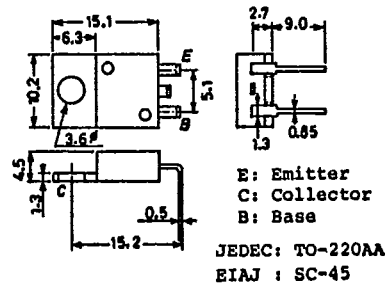
* The 2SB514, 515/2SD330, 331 are classified by 1A h_{FE} as follows

40	C	80	60	D	120	100	E	200	160	F	320
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Case Outline 2010A
(unit:mm) [2SB514/2SD330]

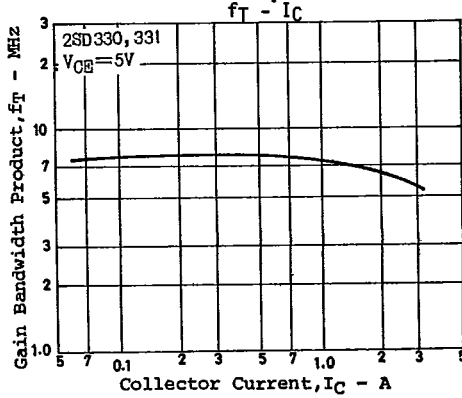
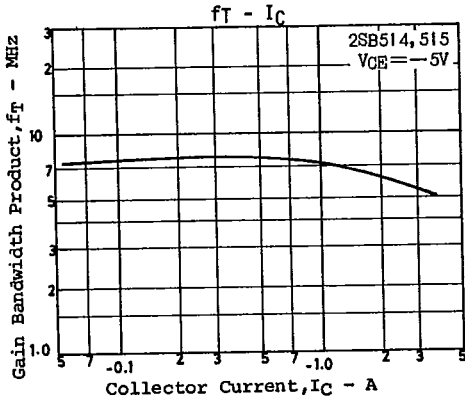
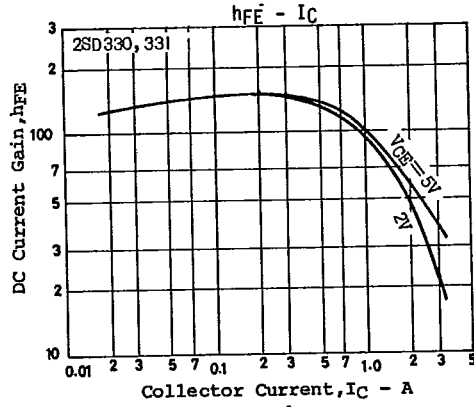
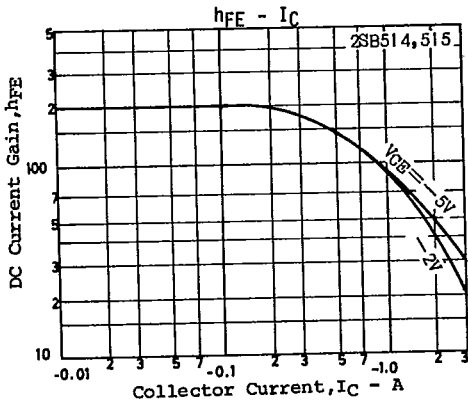
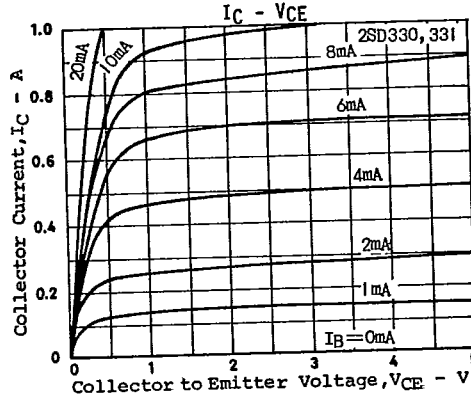
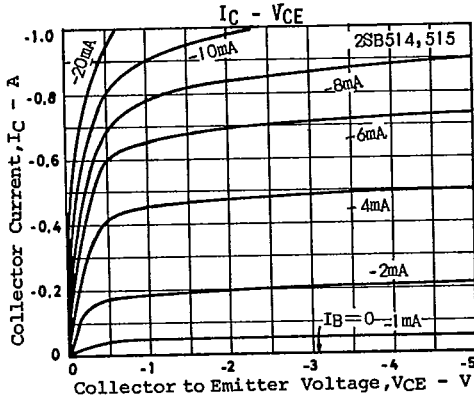
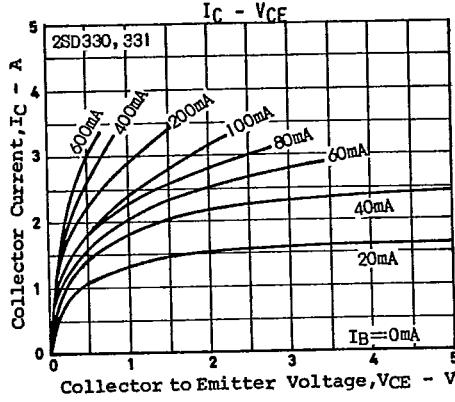
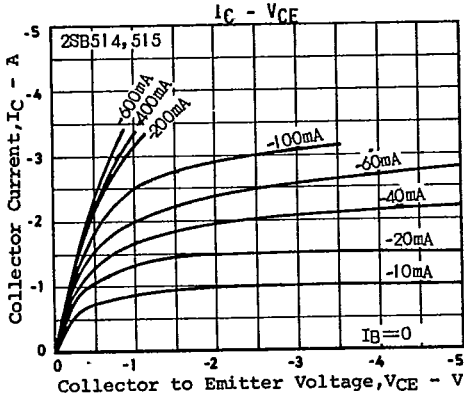


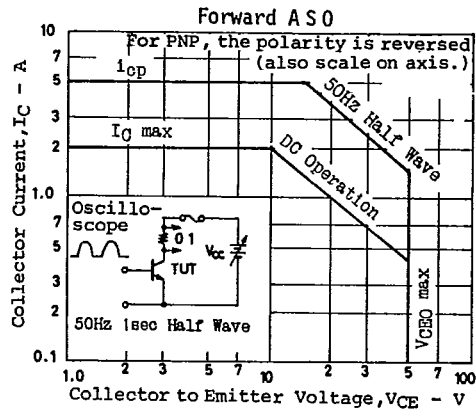
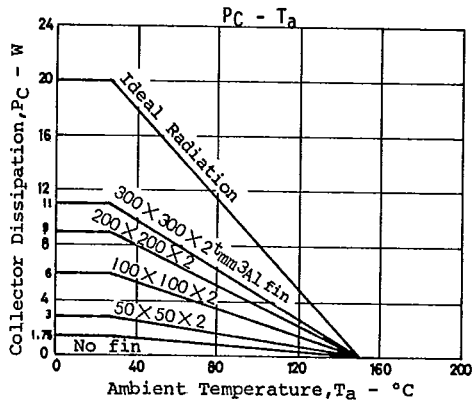
Case Outline 2012
(unit:mm) [2SB515/2SD331]



The 2SB515/D331 are scheduled to be discontinued soon. Use the 2SB514/D330, instead of the 2SB515/D331, in new applications where you are planning to use the 2SB515/D331.

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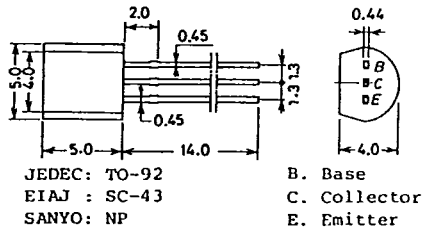


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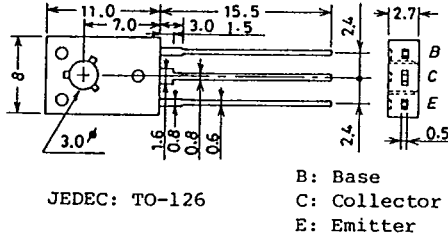
CASE OUTLINES AND ATTACHMENTS

- All of Sanyo Transistor case outlines are illustrated below.
- All dimensions are in mm, and dimensions which are not followed by min. or max. are represented by typical values.
- No marking is indicated.

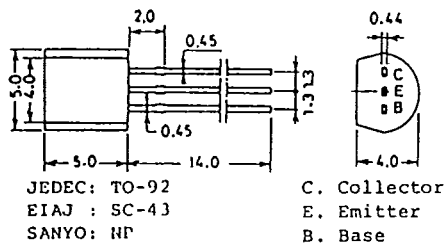
Case Outline-[2003A]
unit:mm



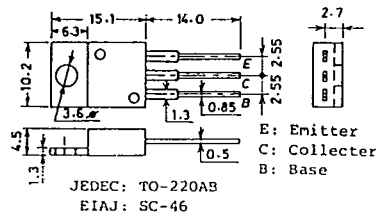
Case Outline-[2009A]
unit:mm



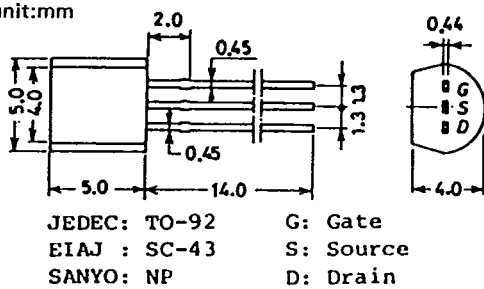
Case Outline-[2004A]
unit:mm



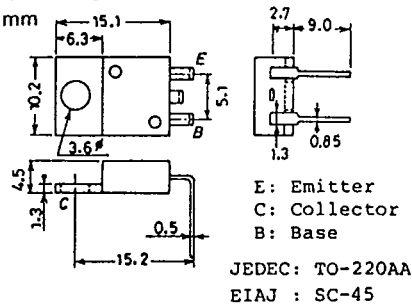
Case Outline-[2010A]
unit:mm



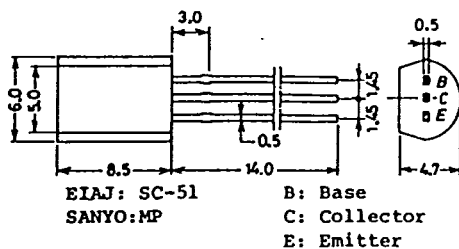
Case Outline-[2005A]
unit:mm



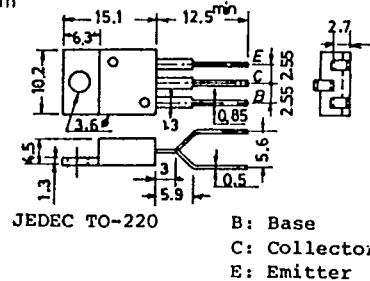
Case Outline-[2012]
unit:mm



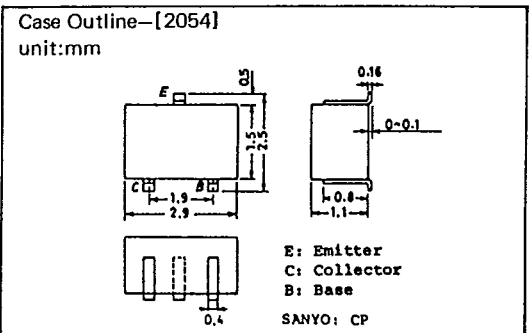
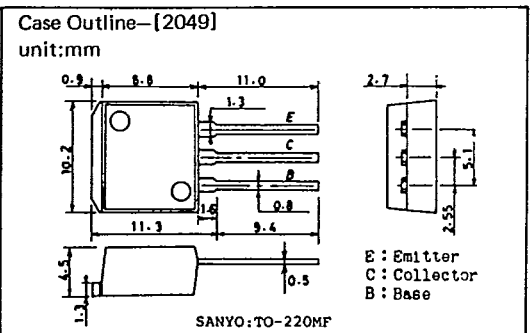
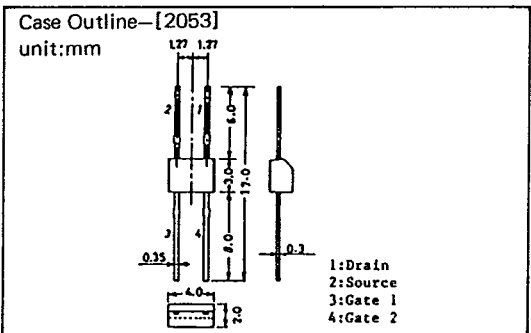
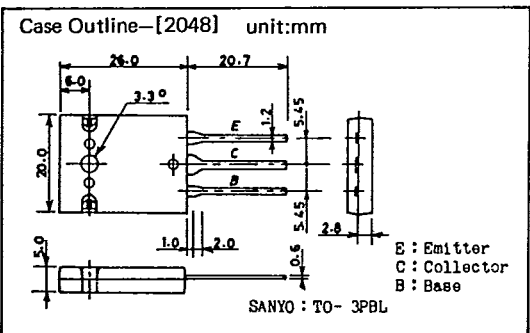
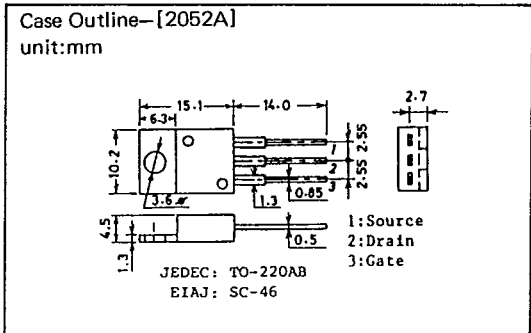
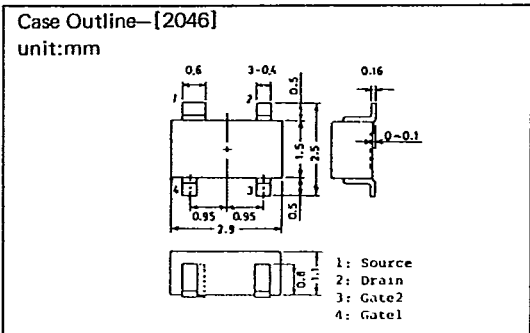
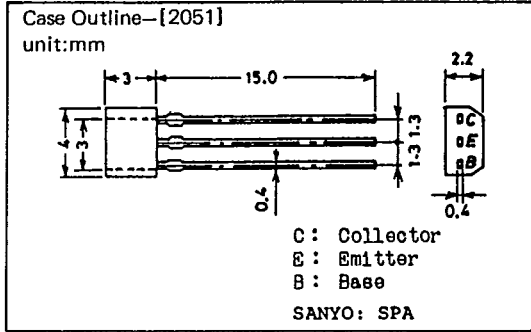
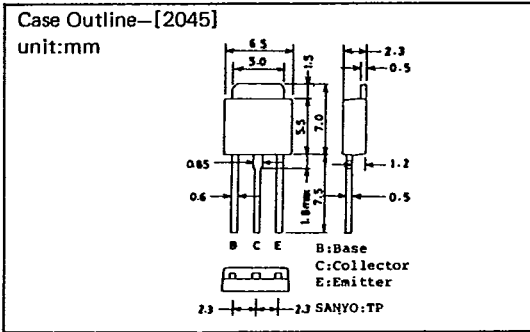
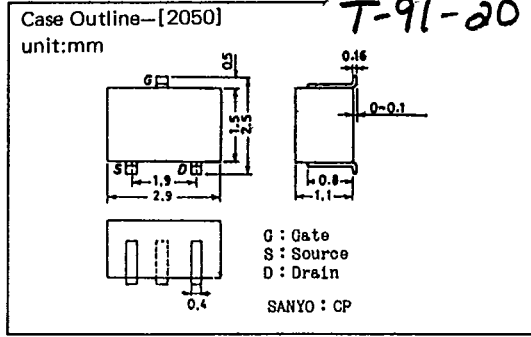
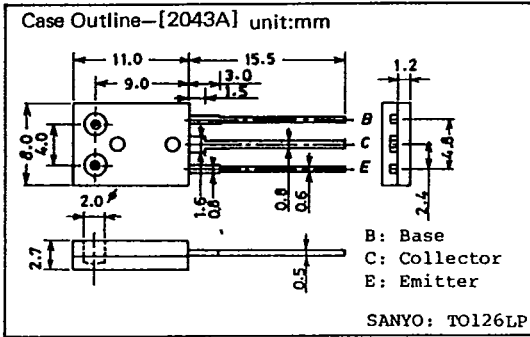
Case Outline-[2006A]
unit:mm



Case Outline-[2013]
unit:mm



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